

Technical Data Data Sheet N0666, Rev. - **Green Products** 

# **15MQ060N SCHOTTKY RECTIFIER**

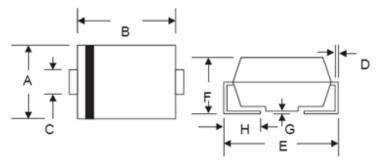
### **Applications:**

- Disk Drives
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Battery Charging

### Features:

- Small foot print, surface moutable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Mechanical Dimensions (In mm / Inches):



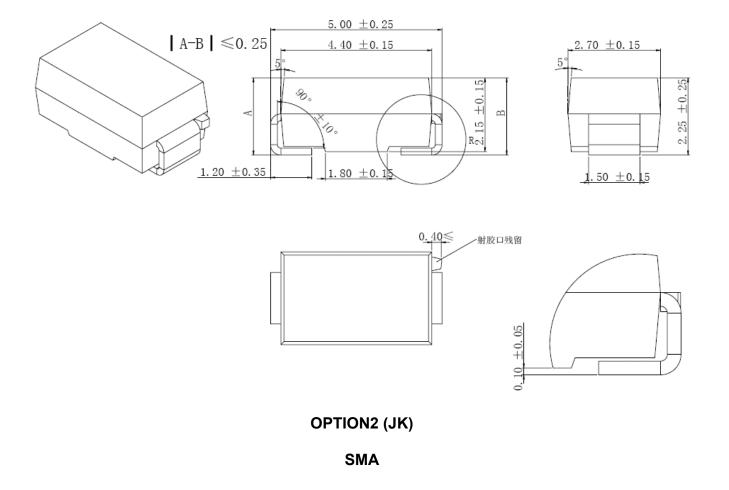
SMA/DO-214AC					
Dim	Min	Мах	Min	Мах	
Α	2.50	2.90	0.098	0.114	
в	4.00	4.60	0.157	0.181	
С	1.40	1.60	0.055	0.063	
D	0.152	0.305	0.006	0.012	
E	4.80	5.28	0.189	0.208	
F	2.00	2.44	0.079	0.096	
G	0.051	0.203	0.002	0.008	
н	0.76	1.52	0.030	0.060	
	In mm		In inch		

### **OPTION 1**

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#### Technical Data Data Sheet N0666, Rev. -Marking Diagram:

Where XXXXX is YYWWL

S	= Device Type
D	= Package Type
15	= Forward Current (1.5A)
Н	= Reverse Voltage (60V)
ΥY	= Year
WW	= Week
L	= Lot Number

SD15H XXXXX

Cautions: Molding resin Epoxy resin UL:94V-0

# **Ordering Information:**

Device	Package	
SD15H	SMA (Pb-Free)	5000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	60	V
Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle $@T_L=105^{\circ}C$ , rectangular wave form On PC board 9mm <sup>2</sup> island	2.1	А
Peak One Cycle Non- Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	60	А



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## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 1.5 A, Pulse, T <sub>J</sub> = 25 °C	0.5	V
		@ 3 A, Pulse, T <sub>J</sub> = 25 °C	0.6	
Reverse Current *	I <sub>R1</sub>	$@V_R = Rated V_R$ , Pulse,	1.0	mA
		T <sub>J</sub> = 25 °C		
	I <sub>R2</sub>	$@V_R = Rated V_R$ , Pulse,	50	mA
		T <sub>J</sub> = 125 °C		
Junction Capacitance	CT	@V <sub>R</sub> = 10V, T <sub>C</sub> = 25 °C	250	PF
		f <sub>SIG</sub> = 1MHz		
Voltage Rate of Change	dv/dt	-	10,000	V/µs

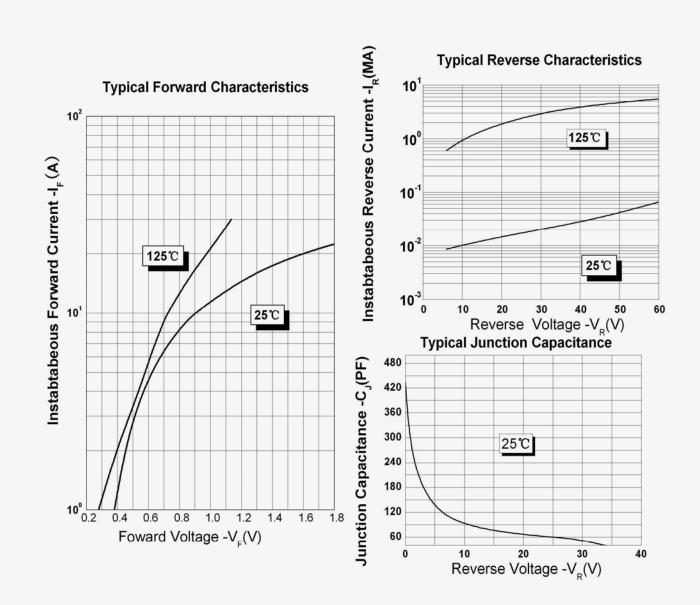
\* Pulse Width < 300 $\mu$ s, Duty Cycle < 2%

### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	ΤJ	-	-55 to +125	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +125	O°
Maximum Thermal Resistance Junction to Ambient	$R_{ heta JA}$	DC operation	80	°C/W
Approximate Weight	wt	-	0.11	g
Case Style		SMA		•



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